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IGBT Gate Drive Unit VLA592-01R



Mar.2017



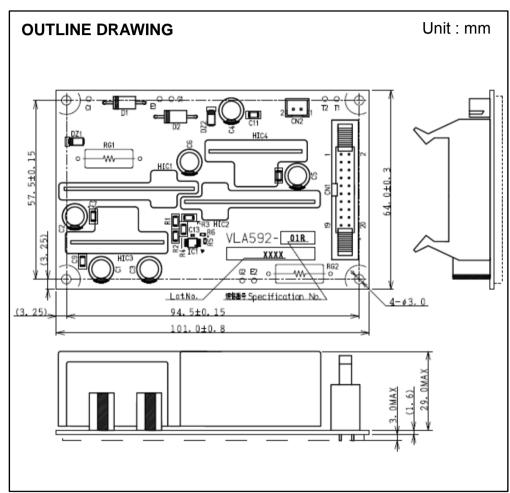
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FEATURE

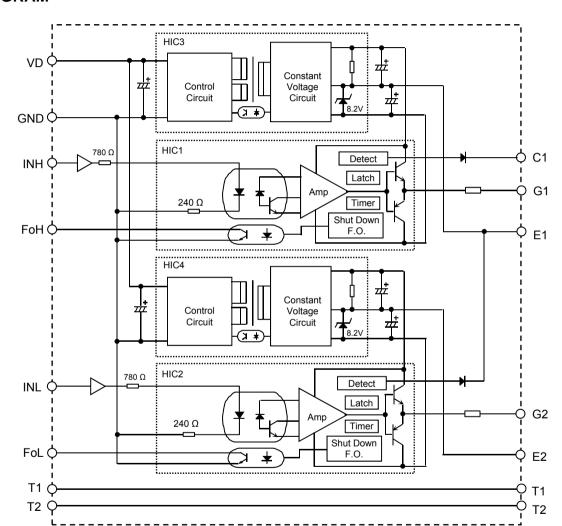
Possible to mount on the IGBT package (2 in 1 package)
Built in the isolated DC-DC converter for gate drive
Built in short circuit protection (with soft shut down)
Electrical isolation voltage is 2500Vrms (for 1 minute)
One way power supply system for drivers and input signal (VD=15V)

TARGETED IGBT MODULES

VCES = 650V series ~ 600A class VCES = 1200V series ~ 450A class







BLOCK DIAGRAM

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Symbol	Parameter	Conditions	Ratings	Unit	
VD	Supply voltage	DC	15.75	V	
VI	Input signal voltage	Applied between GND - INH,INL	19	V	
IOHP		Pulse width 2us	-5	А	
IOLP	P Gate peak current		5	А	
Viso	Isolation voltage	Sine wave voltage 60Hz, for 1min	2500	Vrms	
Topr	Operating temperature	No condensation allowable	-20 ~ 70	deg C	
Tstg	Storage temperature	No condensation allowable	-25 ~ 85	deg C	
IFo	Fo pin output sink current	-	10	mA	
VFo	Fo pin voltage	Applied between GND – FoH,FoL	50	50 V	
Idrive Gate drive current		Gate average current (Per one circuit)	83	mA	

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ELECTRICAL CHARACTERISTICS

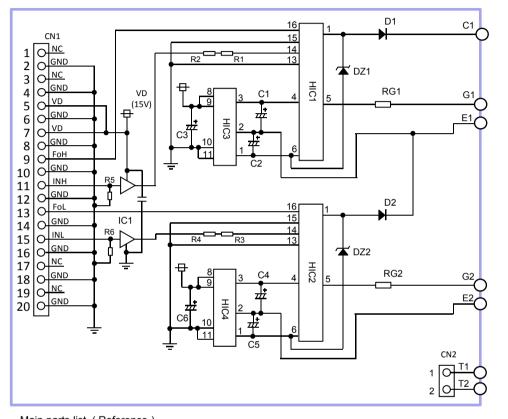
(unless otherwise noted, Ta=25C, VD=15V)

Symbol	Parameter	Conditions	Limits			Unit
Cymbol	i didineter	Conditions		Тур	Max	Onic
VD	Supply voltage	Recommended range	14.25	15	15.75	V
f	Switching frequency	Recommended range	-	-	20	kHz
IFo	Fo output current	Recommended range	-	-	5	mA
RG	Gate resistance	-	-	-	-	Ω
VI_H	Input signal high threshold	-	1.8	2.1	2.4	V
VI_L	Input signal low threshold	-	0.9	1.2	1.5	V
VOH	Plus bias voltage	-	14.5	16.0	17.5	V
VOL	Minus bias voltage	-	-9.0	-8.0	-7.0	V
tPLH	"L-H" propagation time	VI = 15V	0.2	0.45	0.8	us
tPHL	"H-L" propagation time	VI = 15V	0.2	0.4	0.7	us
t_timer	Timer	Between start and clear (under input signal "OFF")	1	1.4	2	ms
td_Fo	Fault out delay time	IFo=2.5mA	-	6.5	10	us
VSC	SC detect collector voltage	IGBT collector voltage	15	-	-	V



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INNER CIRCUIT



Main parts list	: (Referenc	e)
HIC1,2	VLA520-01	R
HIC3,4	VLA106-15	5252
IC1	UCC27524	A
DZ1,2	30V, 500m	W class
D1,2	RP1H	
CN1	3428-6002	LCPL
CN2	B2B-XH-A	
R1,2,3,4	390 ohm	1/4W
R5,6	10k ohm	1/10W
RG1,2		3W

ISAHAYA ISAHAYA TI	
SanKen 3M	

JST

CN1		
PinN.o.	Pin name	
1	NC	
2	GND	
3	NC	
4	GND	
5	VD	
6	GND	
7	VD	
8	GND	
9	FoH	
10	GND	
11	INH	
12	GND	
13	FoL	
14	GND	
15	INL	
16	GND	
17	NC	
18	GND	
19	NC	
20	GND	

CN2			
Pin N.o.	Pin name		
1	T1		
2	T2		

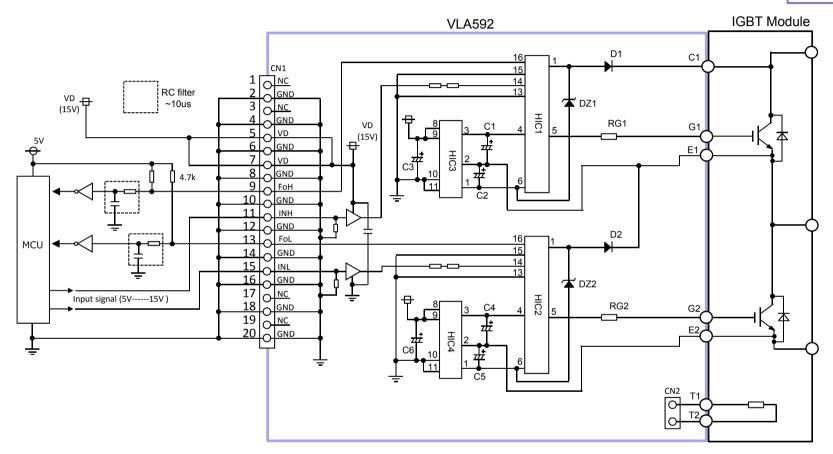


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APPLICATION EXAMPLE

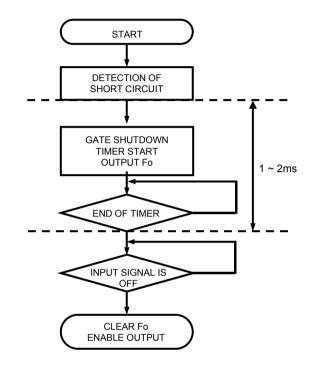
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OPERATION FLOW ON DETECTING SHORT CIRCUIT

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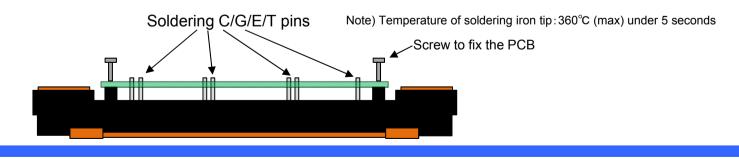


(1)In case the gate signal is "ON" and the collector voltage is high, the gate driver will recognize the circuit as short circuit and immediately reduce the gate voltage.(Soft shut down) Besides, put out an Fo sign which inform that protection circuit is operating.

(2)The protection circuit return to ordinary condition if input signal is OFF when the predetermined time(1~2ms) passed.

(OFF period is needed more than 40us.)

INSTALLATION OF THE PCB ON IGBT MODULE





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Keep safety first in your circuit designs!

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